GOVT. HOLKAR (MODEL AUTONOMOUS) SCIENCE COLLEGE, INDORE



(An ISO 9001:2015 & ISO 14001:2015 Certified Instituion)





SSR DOCUMENT

2017-18 TO 2021-22

CRITERION-5

Student Support and Progression

Metric No.: 5.1.2

Document Title:

Sample of structured course content

Part- A: Introduction for Code

	Govt. Holkar (Model, Autonomous) Science College, Indore
	Department of Forensic Science
	SYLLABUS SESSION-2021-2022
	M.Sc. – 1st SEMESTER
Title	e of the Paper (Course): Forensic Science and Criminal Justice System Course Code: FS-11
Course O	bjective
1: To knov	w basic principle & understanding of forensic science and criminal justice system
2: To knov	v understanding of crime scene management.
Course O	utcomes - After completion of this paper students will come to -
C01	Explain Fundamental principle and scope of forensic science
C02	Identify the importance and effects of preserving the crime scene
C03	Summarize the various theories of crime.
C04	Recognize the different sections of IEA, IPC and CRPC
C05	Describe relationship between courts, forensic science and police.
Part B: C Unit 1	Introduction to Forensic Science: Forensic Science: Definition, Nature and
	Scope, Basic principles and its significance, Development of Forensic Science in India and abroad, Functions, Responsibilities and ethics of Forensic Scientist, Organizational structure of Forensic Science Laboratories at Central & State levels, Ethics in Forensic Science Institutions in India.
Unit 2	Crime: Definition, Types, Theories of Causation of Crime- Pre-classical and Neo-classical, Constitutional, geographic, economic, psychological and sociological, Multiple Causation approach, General Factors of Crime and forms of punishment in brief, causes prevention and characteristics of criminals. Criminal Justice System: Police Organization at District, State and Central Level. Organization of courts in India. Jurisdiction of Court in criminal cases, prosecution, FIR, Case Diary, Roznamacha Report Writing and Evidence Evaluation: Report formats of crime scene and laboratory findings. Court Testimony: Admissibility of expert testimony, pro court preparation & Court appearance, examination in-chief & re-examination, cross-examination.
Unit 3	Crime Scene Management and Evidences: Scene of Crime: Classification, protection of scene of crime, preservation of scene of crime – photography, videography and sketching method, Response to Special Crime scene (Man-made and natural). Legal and Human Consideration during investigations. Evidences: Meaning, Types, Searching Methods, Chain of Custody
Unit 4	Collection, Preservation, Packing and Forwarding of Evidences: Collection, preservation, packing and forwarding from scene of crime, Victim and deceased body in cases of Homicide Investigation, Death due to burning, Rape and Sexual offences, Hanging (Suicidal, Homicidal and Accidental), Drowning, Human Remains, Human Poisoning (Fetal and Survival), Death by

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DEPARTMENT OF FORENSIC SCIENCE SESSION-2021-22

	Firearms, Firearm exhibits, Forged, Torn and Charred Documents, Bank Notes, Capturing of Volatile evidences in computer fraud and Cyber Crime, audio and video CCTV Footage, Transportation of Digital Evidences, Blood, Semen and other biological Stains, tissues, Viscera, Hair& Fibre, Glass, Soil and Dust, Petroleum product, Latent Fingerprint, Drug and Poisons, Metals
Unit 5	Indian Penal Code: Introduction, general exceptions, offences against person, offences against property, Attempt to suicide, Sexual offences. Criminal Procedure Code: Introduction and General idea of sections: 291-93, 154,155,156,157,158,159,160,161,162,172,173,174,175 and 176. Indian Evidence Act: Introduction and General idea of sections: 32,45, 46,47,57,58,60,73,135,136,137, and 159. Juvenile Delinquency: Brief Introduction: Juvenile Justice Act, 2000, POCSO Act, 2019, Child and Adolescent Labor Act, 1986, Case Studies.

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Part C: Learning Resources

- 1. Saferstein: Criminalistics An Introduction to Forensic Science, Prentice Hall Inc. USA (1995).
- 2. C.G.G. Aitken and D.A. Stoney: The use of statistics in Forensic Science, Ellis Harwood Limited, England (1991)
- 3. James, H.S. and Nordby, J.J.; Forensic Science; an Introduction to scientific and Investigative Techniques, CRC press, USA (2003)
- 4. O'Hara & Osterberg: An introduction to Criminalistics.
- 5. Forest: Forensic Science, An Introduction.
- 6. Lee, Honry: Advance in Forensic Science.
- 7. Sharma J.D. Vidhivigyan Avem Vish Vigya.
- 8. Sharma J.D. Apradho ka Vigyanic Anveshan.
- 9. Sharma B.R. Forensic Science in Criminal Investigation and trials.
- 10.Mordby, J. Deed Reckoning The Art of forensic Science detection, CRC press LLC, Boca Raton FL, CRC press (2000)
- 11.Ram Ahuja: criminology, Rewal Publ. Jabalpur (2000).
- 12.Indian Penal Code
- 13. Criminal Procedure Code
- 14.Indian Evidence Act.

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Part D – Assessment and Evalu Suggested Continuous Evaluatio	n Methods: By Presentation, PPT, By Test, By	written
Exam		
Maximum Marks: 100 Continuous Comprehensive Eva	huation (CCE): 25 External Exam (EE): 75	
Internal Assessment: Continuous Comprehensive Evaluation (CCE): 25	Class Test Assignment/Presentation	25
External Assessment: External Exam: 75 Time: 3 hours	75	75
Section 19 Section and Advantage		100

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Part A: Introduction for Code:

	Govt. Holkar (Model, Autonomous) Science College, Indore Department of Forensic Science
	SYLLABUS SESSION – 2021-2022
	M.Sc. – 1st SEMESTER
Title of the	e Paper (Course): Forensic Medicine Course Code: FS-12
	Tupe (Course)
Course Ol 1: To unde 2: To have and	rstand the basic concept of forensic medicine and legal procedures. knowledge of personal identity traits, post-mortem examination, injuries different modes of death.
Course O	utcomes - After completion of this paper students will come to-
C01	Describe the Forensic medicine and legal procedures of court.
C02	Link the parameters to fix personal identity.
C03	Relate the post-mortem changes & their medico legal importance.
C04	Interpret the death and its Medico-legal Aspect
C05	Illustrate Post-mortem examination and sexual offences.
Part B: C	Forensic Medicine: Definition of Forensic Medicine and Medical
	Jurisprudence, Brief knowledge about legal procedure in court, inquest, Subpoena & oath of medical expert, Criminal court and their powers Recording of medical expert evidence in courts. Professional Negligence, Types of medical evidence, Kinds of witness and rules for giving evidence.
Unit 2	Personal Identity: Definition and importance, parameters contributing to personal identity- Race, Sex, Age, Complexion, Features & Photographs, Anthropometry, Stature, Scar, Hair, Teeth, Wounds, Foetal Age, Bite Marks, Fingerprints, Footprints, Tattoo marks, Birth marks, Occupational Marks, Handwriting, Clothes and Ornaments, Voice & Speech, DNA, Disputed paternity.
Unit 3	Wounds & Injuries: Introduction, its types, Mechanical Injury- Abrasion, Contusion, Laceration, Incised wound, Stab, Self-inflicted and fabricated, Firearm Injury, Bomb explosion wounds. Regional Injuries: Head Injury, Skull, Traffic Accident, Air craft, Boxing, Railway, Mass-Disasters. Medico-Legal aspects, post mortem & ante mortem wounds: General characteristics of injuries from cold, heat, burns, scalds, lightning, electricity and radiation, Forensic Importance of Wounds.
Unit 4	Death and its Medico- legal aspects: Modes of death (Coma, Syncope, Asphyxia), Sudden death, Post – Mortem Changes: Cessation of vital functions, Changes in the Eyes, Skin and muscles. Temperature, post- mortem lividity, Rigor mortis

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DEPARTMENT OF FORENSIC SCIENCE SESSION-2021-22

	Decomposition, Adipocere, Mummification, Post-mortem Interval, Estimation time since death. Mechanical Asphyxia: Hanging and its types, Ligature marks and its examination, Strangulation, Bansadola, Garroting, Mugging, Suffocation, Gagging, Choking and Café coronary. Traumatic Asphyxia: Burking, Postural Asphyxia, Sexual Asphyxia, Drowning (Ante Mortem and Post Mortem)
Unit 5	Post-Mortem Examination: Importance, external & Internal examination in brief, Viscera & its preservation, Examination of decomposed and mutilated bodies, Exhumation, Cause of death Sexual Offences: Sexual offences, Virginity and Pregnancy

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Part C: Learning Resources:

- 1. Modi J. S.: Medical Jurisprudence and Toxicology.
- 2. Taylor : Medical Jurisprudence
- 3. Parikh C.K.: Chikitsa Nyaya Shastra Aur Vish Vigyan.
- 4. Kieth Simpsen & Bernard Knight: Forensic Medicine
- 5. Poison: CJ, DJ, Gee, B. Knight: Forensic Medicine
- 6. Reddy: Forensic Medicine

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Part D – Assessment and Evaluation Suggested Continuous Evaluation Meth Maximum Marks: 100 Continuous Comprehensive Evaluation	ods: By Presentation, PPT, By Test, By writt	en Exam
Internal Assessment: Continuous Comprehensive Evaluation (CCE): 25	Class Test Assignment/Presentation	25
External Assessment: External Exam: 75 Time: 3 hours	75	75
		100

27.11.2021

Govt. Holkar (Model, Autonomous) Science College, Indore

Department of Electronics Syllabus Session 2021-22

Class: B.Sc. I Sem Subject: Electronics Marks: 75 + (CCE) 25 = 100

Credit: 4

Paper: Core (Major) I

Title of Paper: Semiconductor Devices

Code of the Paper: C108-1

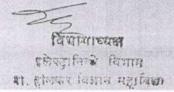
		Part A: Introduction					
1	Pre-requisite (if any)	To study this course, a student must have had the subject Science in class इस पाठ्यक्रम का अध्ययन करने के लिए विद्यार्थियों को 12 वी कक्षा में विज्ञान वि आवश्यक है। This course can be opted as an elective by the student of following sub	षय का होन				
2	Course Objectives	To know the basic knowledge of semiconducting material and devices					
	Course Learning	1: Analyze the behavior of semiconductor materials अर्धचालक पदार्थों के ट्यवहार का वर्णन करना।					
	Outcomes	2: Reproduce the I-V characteristics of diode/ BJT/MOSFET devices डायोड/BJT/ मॉसफेट युक्तियों का I-V अभिलाक्षणिक आरेखित करना					
		3: Apply standard devices models to explain/ calculate critical internal par of semi-conductor devices. अर्धचालक युक्तियां पर मानक युक्ति मॉडल को प्रदान कर वर्णित करना त					
		महत्वपूर्ण मापदंडो का पता करना। 4: Categorize the behavior and characteristics of power devices, such as, etc. पावर यक्तियां जैसे SCR/UJT आदि के व्यवहार तथा अभिलाक्षणिक का वर्ष Part B-Content of the Course भाग ब - पाठयक्रम की विषयवस्त					
То	tal No. of Lect	ures-Tutorials-Practical (in hours per week):60 L-T-P: 2-0-0					
	ख्यानी- टयटीरि nit	(यल -प्रायोगिक कक्षाओं की कल संख्या (प्रति सप्ताह घंटे) : 60 L-T-P: 2-0-0 Topics	No. of Lectures				
	Structure Mass, De Semicone Semicone and Dop Carrier	ductor Basics: Introduction to Semiconductor Materials, Crystal, Planes and Miller Indices, Energy Band in Solids. Concept of Effective ensity of States. Carrier Concentration at Normal Equilibrium in Intrinsic ductors. Derivation of Fermi Level for Intrinsic & Extrinsic ductors, Donors, Acceptors, Dependence of Fermi Level on Temperature ing Concentration, Temperature Dependence of Carrier Concentrations. Transport Phenomena: Carrier Drift, Mobility, Resistivity, Hall Effect, a Process, Einstein Relation, Current Density Equation, Carrier Injection, on and Recombination Processes, Continuity Equation.	14				

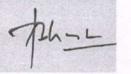
विमागाज्यक

SESSION 2021 - 22

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	सेमीकंडक्टर आधारभूतः सेमीकंडक्टर मैटेरियल्स का परिचय, क्रिस्टल स्ट्रक्चर, प्लेन	
	और मिलर इंडेक्स, ठोस में उर्जा बैंड, प्रभावी द्रव्यमान की अवधारणा, सघनता की अवस्था	
	। आंतरिक अर्धचालकों में सामान्य साम्यावस्था पर वाहक सांद्रता । अर्धचालकों में आंतरिक	
	और बाह्य के लिए फर्मी स्तर की व्युत्पत्ति। दाता, ग्राही। तापमान और डोपिंग पर फर्मी स्तर	
	की निर्भरता, वाहक सांद्रता की तापमान निर्भरता। वाहक परिवहन घटना :वाहक ड्रिफ्ट,	
	विचलता, प्रतिरोधकता, हॉल प्रभाव, विसरण क्रिया, आइंस्टीन संबंध, धारा सघनता	
	समीकरण, वाहक अन्तःक्षेपण , जनरेशन तथा रेकोम्बिनेशन की अवधारणा, सातत्य	
2	P-N Junction Diode: Formation of Depletion Layer, Space Charge at a junction, Derivation of Electrostatic Potential Difference at Thermal Equilibrium, Depletion Width and Depletion Capacitance of an Abrupt junction. Concept of Linearly Graded junction, Derivation of Diode Equation, and I-V Characteristics, Zener Diode, Zener and Avalanche junction Breakdown Mechanism. LED, Tunnel diode, Varactor diode, Solar cell, Schottky Diode: working, circuit symbol, characteristics and applications.	14
	पीएन संधि डायोड: PN संधि डायोड अवक्षय परत का निर्माण, संधि पर स्पेस चार्ज, तापीय	
	साम्यावस्था पर इलेक्ट्रोस्टेटिक विभवान्तर के सूत्र व्यूत्पति, अब्रप्ट जंक्शन कि अवक्षय चौड़ाई	
	तथा अवक्षय संधारित्र, रेखीय ग्रेडेड संधि की अवधारणा, डायोड समीकरण की व्यूत्पति तथा	
	धारा-विभव अभिलाक्षणिक, जेनर डायोड, जेनर तथा ऐवेलॉनची भंजन,LED , टनल डायोड,	
	वैरेक्टर डायोड, सोलर सेल, शॉर्टकी डायोड: प्रतीक, कार्यविधि , अभिलाक्षणिक तथा	
	अन्प्रयोग.	
3.	Bipolar Junction Transistors (BJT): PNP and NPN Transistors, Basic Transistor Action, Emitter Efficiency, Base Transport Factor, Current Gain, Energy Band Diagram of Transistor in Thermal Equilibrium, Quantitative Analysis of Static Characteristics (Minority Carrier Distribution and Terminal Currents). Base-Width Modulation, Modes of operation, Input and Output Characteristics of CB, CE and CC Configurations. Metal Semiconductor Junctions: Ohmic and Rectifying Contacts.	14
5	द्विधुवी जंक्शन ट्रांजिस्टर (BJT): PNP और NPN ट्रांजिस्टर, ट्रांजिस्टर की क्रिया की	
	अवधारणा, उत्सर्जक दक्षता, आधार ट्रांसपोर्ट गुणांक, धारा लाभ, तापीय साम्यावस्था में	
	ट्रांजिस्टर का ऊर्जा बैंड चित्र, स्थैतिक विशेषताओं मात्रात्मक विश्लेषण (अल्पसंख्याक	
	आवेश वाहको का वितरण तथा टर्मिनल धारा), बेस विड्थ माड्यूलेशन, कार्यप्रणाली,	
	उभयनिष्ठ आधार, उभयनिष्ठ उत्सर्जक, उभयनिष्ठ संग्राहक अभिविन्यासओं की इनप्ट तथा	
	आउटपुट अभिलाक्षणिक, धातु अर्धचालक संधि: ओमिक तथा रेक्टिफाइंग कॉन्टैक्ट्स।	
4	Field Effects Transistors: JEET, Construction, Idea of Channel Formation, Pinch-OFF and Saturation Voltage, Current-Voltage Output Characteristics. MOSFET, type of MOSFETs, Circuit Symbols, Working and Characteristic curves of Depletion type MOSFET (both N channel and P channel). Complimentary MOS (CMOS).	18





Power Devices: UJT: Basic construction and working, Equivalent circuit, intrinsic Standoff Ratio, Characteristics and relaxation oscillator-expression.

SCR: Construction, Working and Characteristics, Triac, Diac, IGBT, MESFET: circuit symbols, basic constructional features, operation and application.

क्षेत्र प्रभाव ट्रांजिस्टर: JFET, संरचना, चैनल निर्माण की अवधारणा, पिंच-ऑफ तथा संतृष्ति विभव, धारा विभव आउटपुट अभिलाक्षणिक। MOSFET, MOSFETs के प्रकार। परिपथ प्रतीक, डिप्लेशन टाइप MOSFET (N चैनल तथा P चैनल) तथा एन्हेंस्मेंट टाइप MOSFET (N चैनल तथा P चैनल) कि कियाविधि तथा अभिलाक्षणिक। कॉम्प्लीमेंट्री MOS (CMOS). पाँवर युक्तियाँ: UJT: आधारभूत संरचना तथा कार्यविधि, समतुल्य परिपथ, इंट्रिंसिक स्टैंडऑफ अनुपात, रिलेक्सेशन दोलित्र का समीकरण तथा अभिलाक्षणिक। SCR: संरचना, कार्यविधि तथा अभिलाक्षणिक, Triac, Diac, IGBT, MESFET: परिपथ, प्रतीक, आधारभूत संरचना, कार्यविधि तथा अनुप्रयोग।

Keywords/Tags:

Part C-Learning Resources भाग स - अनशंसित अध्ययन संसाधन

Text Books, Reference Books, Other resources

पाठय पस्तके, संदर्भ पस्तके, अन्य संसाधन

Suggested Readings:

अनशंसित सहायक पस्तकें / ग्रन्थ/अन्य पाठय संसाधन/पाठय सामग्री

- 1. Malvino A.P., Electronic Principles, Tata Me Graw Hill pub, 7th Ed., 2017
- 2. Mehta V.K., Principles of Electronics, S. Chand & Co, 2007
- 3. S.M. Sze, Physics of Semiconductor Devices: Physics and Technology, 2nd Edition, Wiley India edition, 2008.
- 2 Suggestive digital platforms web links

अनुशंसित डिजिटल प्लेटफॉर्म वेब लिंक

National Digital Library: https://ndl.iitkgp.ac.in/

Suggested equivalent online courses:

1. https://www.coursera.org/

2. Lectures: MIT open courseware, MIT Course Number 6.012

https://ocw.mit.edu/courses/electrical-engineering-and-computer-science/6-012-microelectronic-devices-and-circuits-fall-2009/lecture-notes/

3. NPTEL E-Learning Courses: https://nptel.ac.in/courses/117/102/117102061/

Part D- Assessment and Evaluation

भाग द - अनशंसित मल्यांकन विधियां

Suggested Continuous Evaluation Methods:

अन्शंसित सतत मृल्यांकन विधियाँ:

Maximum Marks:100, अधिकतम अंक :100

Continuous Comprehensive Evaluation (CCE): 25marks

सतत व्यापक मृल्यांकन) CCE) अंक : 25

End Term Exam (ETE): 75marks

मख्य सिद्धांत परीक्षा(ETE) अंक: 75

Internal Assessment: C

Class Test Assignment/Presentation

आंतरिक मृल्यांकन :

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विधागाध्यास

इलेक्ट्रानिको विभाग

SESSION 2021 - 22

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Continuous Comprehensive Evaluation (CCE):25 सतत व्यापक मल्यांकन) CCE):		10 =25
External Assessment: आकलन University Exam Section :75 Time: 02.00 Hours विश्वविद्यालय परीक्षा 75 समय 02: 00 घंटे	Section(A): Three Very Short Question (50 Words Each) (अनुभाग-अ): तीन अति लघु प्रश्न (प्रत्येक 50 शब्द) Section (B): Four Short Questions (200 Words Each) (अनुभाग-ब): चार लघु प्रश्न (प्रत्येक 200 शब्द) Section(C): Two Long Questions (500 Word Each) (अनुभाग-स): दो दीर्घ उत्तरीय प्रश्न (प्रत्येक 500 शब्द)	$03 \times 03 = 9$ $04 \times 09 = 36$ $02 \times 15 = 30$ Total 75
Any remarks/ suggestions:		

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विधानाध्यक्ष

इलेक्ट्रानिश्के विद्यास मा. होलकर विद्याल महाविधाः इन्होर Ah->

Class: B.Sc. I Sem Subject: Electronics Marks: 75 + (CCE) 25 = 100

Credit: 2

Paper: Practical (Major)

Code of the Paper: P1

Title of Paper: Semiconductor Devices Laboratory

		Part A Introduction							
1	Pre-requisite (if any)	To study this course, a student must have had the subject Science in class 12t इस पाठ्यक्रम का अध्ययन करने के लिए विद्यार्थियों को 12 वी कक्षा में विज्ञान विष का होना आवश्यक है। And have opted SI-ELEC2G. This course can be opted as an elective by the students of following subjects.							
2	Course Objectives	To understand practical behavior of Semiconductor Devices.							
	Course Learning Outcomes	On completion of this course, learners will be able to: 1. Examine the characteristics of basic semiconductor devices. आधारभूत अर्धचालक युक्तिओं के अभिलाक्षणिक की जांच करना।							
		2. Perform experiments for studying the behavior of semiconductor devices for circuit design applications. सर्किट डिजाइन अनुप्रयोगों के लिए, अर्धचालक उपकरणों के व्यवहार का अध्ययन करने के लिए प्रयोग करना।							
		3. Calculate various device parameters values from their characteristics. I-V अभिलाक्षणिक माध्यम से युक्तिओं के विभिन्न मा परिकलित करना ।							
		ng the device लिए प्रयोगात्मक							
		Part B- Content of the Course							
Charles Volume Annual Control	THE RESERVE THE PARTY OF THE PA	Tutorials- Practical (in hours per week): 60 L-T-	P: 0-0-2						
Unit	Topics		No. of Lectures						
1	Diode. 2. Study of 3. Study of obtain r _i ,	the I-V Characteristics of Diode – Ordinary and Zener I-V Characteristics of LED. the I-V Characteristics of the CE configuration of BJT and r _o , β. the I-V Characteristics of the Common Base Configuration							

विभागाध्यक इलेक्ट्रानिक विभाग

of BJT and obtain ri, ro, a.

SESSION 2021 - 22

- Study of the I-V Characteristics of the Common Collector Configuration of BJT and obtain voltage gain, ri and ro,
- 6. Study of the I-V Characteristics of the UJT.
- 7. Study of the I-V Characteristics of the SCR
- 8. Study of the I-V Characteristics of the JFET.
- 9. Study of the I-V Characteristics of the MOSFET.
- 10. Study of Characteristics of Solar Cell
- 11. Study of Hall Effect.

Keywords/Tags:

Part C-Learning Resources

भाग स - अन्शंसित अध्ययन संसाधन

Text Books, Reference Books, Other resources

पाठय पस्तके, संदर्भ प्रतके, अन्य संसाधन

Suggested Readings:

अनुशंसित सहायक प्स्तकें / ग्रन्थ/अन्य पाठय संसाधन/पाठय सामग्री

1. S P Chandra, B shashikala, Electronics Laboratory Primer, S. Chand & Co. 2008

2. Harnam Singh, P.S. Hemne, Practical Physics, S Chand & Co, 2000

Suggestive digital platforms web links

अन्शंसित डिजिटल प्लेटफॉर्म वेब लिंक

National Digital Library: https://ndl.iitkgp.ac.in/

Suggested equivalent online courses:

अन्शंसित समकक्ष ऑनलाइन पाठयक्रमः

Virtual Lab: http://vlabs.iitkgp.ac.in/be/

Part D-Assessment and Evaluation

भाग द - अन्शंसित मृल्यांकन विधियां

Suggested Continuous Evaluation Internal Assessment	Marks अंक	External Assessment बाह्य मृल्यांकन	Marks अंक
आंतरिक मूल्यांकन Class Interaction/ Quiz कक्षा में संवाद/प्रशनोत्तरी	10	Viva Voce on Practical प्रायोगिक मौखिक वायवा	15
कदा म संपाद/प्रशंकारारा Attendance उपस्थिति	5	Practical Record File प्रायोगिक रिकार्ड फाइल	10
Assignments (Charts/Model Seminar/ Rural Service/ Technology Dissemination/ Report of Excursion/ Lab Visits/ Survey/ Industrial visit) असाइनमेंट (चार्ट/मॉडल/सेमिनार /ग्रामीण सेवा/प्रौद्योगिकी प्रसार/ध्रमण/ प्रयोगशाला	10	Table work/ Experiments टेबल वर्क/प्रयोग	50
भ्रमण/ औद्योगिक यात्रा) Total	25		75

विध्यमाध्यक्ष

इन्तेयहानिको विशास का.होन्स विशास महाविद्याः SESSION 2021 - 22

Jun -

Class

- M.Sc. Semester - I

Marks 75+25 (CCE) =100

Subject

- Physics

Min. Marks= 26+9=35

Title of the Paper - Classical Mechanics

Paper Code - PH12

Paper -Core 2

Credits- 4

P	a	r	t	-	A

Introduction for Code - PH12

	SUBJECT: PHYSICS (CLASSICAL MECHANICS)		
Pre-requisite (if any)	B.Sc. with Physics as one of the Subject		
Course Objectives	To impart knowledge about various fundamentals of classical mechanics to study Physics problems		
Course Learning Outcomes (CLO)	 After the completion of the course student will be able to understand: To optimize the variables and learn how symmetries lead to constant of motion. The equivalence between Newtonian mechanic, Lagrangian, Hamiltonian, mechanic and Poisson's Brackets To know the method of contour integration to evaluate definite integrals of varying complexity Theory of small oscillations in coupled system. 		

डी.जी.डी.गुप्ता संयोजक

डॉ.संजय दीक्षित विषय विशेषज्ञ (कंडिका 03)

डॉ.के.एल.जाट विषय विशेषझ • (कडिका 03) डॉ.यदुवेन्द्र चोयल विषय विशेषज्ञ (कंडिका 04)

श्री शैलेष कासलीवाल उद्योगपति (क्रीडिका 05) Market on the state of the stat

	Part B : Contents of the Course	
UNIT-I	Newtonian mechanics of one and many particles systems: Conservation laws, Constraints their classification, Principle of virtual work; D'Almbert's Principle in generalized coordinates, The Lagrange's equation from D'Almbert's Principle. Configuration space, Hamilton's principle deduction from D'Almberts principle, Generalized moment and Lagrangian formulation of the conservation theorems, Reduction to the equivalent one body problem; the equation of motion and first integrals, the differential equation for the orbit.	
UNIT-II	The equations of canonical transformation and generating functions; The Hamilton-Jacobi, Action and Angle variables. Poisson's brackets; simple algebraic properties of Poisson's brackets. The equation of motion in Poisson's Brackets notation. Poisson theorem; Principle of least action. The Kepler problem, Inverse central force field, Rutherford scattering.	
UNIT-III	Theory of small oscillations, Equations of motion, Eigen frequencies and general motion, normal modes and coordinates, Applications to coupled pendulum and linear bistable molecule. Rotating coordinate systems. Acceleration in rotating frames. Coriolis force and its terrestrial astronomical applications, Elementary treatment of Eulerian coordinates and transformation matrices. Angular momentum, inertia tensor. Euler equations of motion for a rigid body. Torque free motion for a rigid body.	
UNIT-IV	Symmetries of space and time. Invariance under Galilean transformation, Covariant four dimensional formulations, 4 -Vectors and 4 - scalers. Relativistic generalization of Newton's laws, 4-momentum and 4 - force, Invariance under Lorentz transformation relativistic mechanics. Covariant Lagrangian, covariant Hamiltonian, Examples.	
UNIT-V	This unit will have a short note question covering all the four units. The students will have to answer any two questions out of the four.	

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डॉ.संजय दीक्षित विषय विशेषज्ञ (कंडिका 03)

डॉ.के.एल.जाट विषय विशेषज्ञ • (कंडिका 03)

डॉ.यदुवेन्द चोयल विषय विशेषज्ञ (कंडिका 04)

श्री शैलेष कासलीवाल उद्योगपति (कंडिका 05) Sherry on the state of the stat

Part C :- Learning Resources

Suggested Readings.

- 1. H.Goldstein (Addison Wesley)-Classical Mechanics
- 2. N.C.Rana&P.S.Jog-Classical Mechanics
- 3. Landu&Lifshitz(Pergamann Press)-Classical Mechanics
- 4. A. Sommarfield(Academic Press)-Classical Mechanics
- 5. R.G. Takwale& P.S. Puranik-Introduction to Classical Mechanics

Part D

Assessment and Evaluation - PH12

Suggested Continuous Evaluation Method

Max. Marks = 100

Continuous Comprehensive Evaluation (CCE)

= 25 Marks

Autonomous College Semester end Examination

= 75 Marks

Internal Assessment:	Class Test	Marks Distribution
Continuous Comprehensive	CCE-I	12.5
Evaluation (CCE):25	CCE-II	12.5
		Total= 25Marks
External Assessment:	Question Paper Based	Marks Distribution
Autonomous College Exam: 75 Marks Time: 3 Hrs	One Question from each unit with 100% Internal	15×5 = 75 Marks
	choice	Total = 75 Marks

Any Remarks/ Suggestion:

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डॉ.संजय दीक्षित विषय विशेषज्ञ (कंडिका 03)

डॉ.के.एल.जाट विषय विशेषज्ञ (कंडिका 03) डॉ.यदुवेन्द्र चोयल विषय विशेषज्ञ (कंडिका 04) बी शैलेष कासलीवाल उद्योगपति (कंडिका 05) Reserved for contract (military con)

Class - M.Sc. Semester - I

Subject - Physics

Title of the Paper - Quantum Mechanics- I

Paper -Core 3

Marks 75+25(CCE) =100

Min. Marks= 26+9=35

Paper Code - PH13

Credits- 4

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Introduction for Code - PH13

SUBJECT: PHYSICS (QUANTUM MECHANICS-I)

Pre-requisite (if any)	B.Sc. with Physics as one of the Subject
Course Objectives	To introduce fundamentals of Quantum Mechanics
Course Learning Outcomes	 After the completion of the course student will be able to understand: The Solution of Schrodinger equation for simple potentials. Representation of state vectors and dynamical variables by Matrix and unitary transformations. Various approximation methods in QM to solve non-exactly solvable problems.

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डॉ संजय दीक्षित विषय विशेषज्ञ (कंडिका 03)

डॉ.के एल.जाट विषय विशेषश • (कंडिका 03) डॉ.यदुवेन्द चोयल विषय विशेषज्ञ (कंडिका 04) त्री शैलेष कासलीवाल उद्योगपति (कंडिका 05) Lucio to

Part B: Contents of the Course	
UNIT-I	Basic Postulates of Quantum Mechanics, equation of continuity, Normality, orthogonality and closure properties of eigen functions, expectation values and Ehrenfest theorem, solution of Schrodinger wave equation for one dimensional (a) Potential well (b) Potential step and (c) Potential barrier.
UNIT-II	Solution of Schrodinger equation for (a) Linear Harmonic Oscillator (b) Hydrogen - like atom (C) Square Well potential and their respective application to atomic spectra, molecular spectra and low energy nuclear states (deutron).
UNIT-III	Linear vector space, concept of Hibert space, bra and ket notation for state vector, representation of state vectors and dynamical variables by matrices and Unitary Transformations (Translation and rotation), Creation and Annihilation operators, Heisenberg uncertainty relation through operators (Schwartz inequality).
UNIT-IV	Angular momentum in quantum mechanics, Eigen values and Eigen function of L_2 and L_z in terms of Spherical Harmonics, commutation relation. Time Independent Perturbation theory. Non-degenerate and degenerate cases.
UNIT-V	Matrix Mechanics: The Schrodinger picture, The Heisenberg picture, The Interaction picture, Linear Harmonic Oscillator (solution using the Schrodinger and Heisenberg Picture)

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डॉ.संजय दीक्षित विषय विशेषज्ञ (कंडिका 03)

डॉ.के.एल.जाट विषय विशेषज्ञ (कंडिका 03) डॉ.यदुवेन्द्र चोयल विषय विशेषज्ञ (संडिका 04) भी शैलेष कासलीवाल उद्योगपति (कडिका 05) Lundy and

Part C:-Learning Resources

Suggested Reading.

- 1. L I Schiff-Quantum Mechanics
- 2. S Gasiorovvicz-Quantum Physics
- 3. B Craseman and J D Powell-Quantum Mechanics
- 4. A P Messiah-Quantum Mechanics
- 5. J. J. Sakurai-Modern Quantum Mechanics
- 6. Mathews and Venkatesan-Quantum Mechanics
- 7.A .K.Ghatak and Loknathan-Quantum Mechanics

Part D

Assessment and Evaluation - PH13

Suggested Continuous Evaluation Method

Max. Marks = 100

Continuous Comprehensive Evaluation (CCE)

= 25 Marks

Autonomous College Semester end Examination

= 75 Marks

Internal Assessment:	Class Test	Marks Distribution
Continuous Comprehensive Evaluation	CCE-I	12.5
(CCE):25	CCE-II	12.5
*		Total= 25Marks
External Assessment:	Question Paper Based	Marks Distribution
Autonomous College Exam: 75 marks Time: 3 Hrs	One Question from each unit with 100% Internal	15×5= 75 Marks
	choice	Total= 75 Marks

Any Remarks/Suggestion:

हाँ.जी.डी.गुप्ता संयोजक डॉ.संजय दीक्षित विषय विशेषज्ञ (कंडिका 03)

डॉ.के.एल.जाट विषय विशेषज्ञ (कंडिका ०३) डॉ.यदुवेन्द्र चोयल विषय विशेषज्ञ (कंडिका 04) श्री शैलेष कासलीवाल उद्योगपति (कंडिएका 05) Quest to